SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 884, REV. -

SILICON RECTIFIER DIE

ULTRAFAST RECOVERY

Electrical Characteristics

Parameter	Symbol	Min.	Max.	Unit
Peak Inverse Voltage	V _{RWM}	400	-	Volts
Max. Average DC Output Current	Ι _ο	-	15	Amps
Max. Forward Voltage Drop @ 30A pulse $T_A = 25^{\circ}C$	V _F	-	1.2	Volts
Reverse Current @ V_{RWM} $T_A = 25^{\circ}C$ $T_A = 150^{\circ}C$	I _R	-	10 1.0	μAmps
Max. Reverse Recovery Time	t _{rr}	-	45	ns
Operating and Storage Temp.	T _{OP} & T _{STG}	-55	+150	°C
Maximum Junction Temperature	T _{JMAX}	-	175	°C

Rectifier Die Outline

minimum.



Bottom side metalization Ag - 30 kA

Top side metalization AI = 25 kA or T_{i} .= 1.2kA, N_i = 1.8kA, A_g = 30kA.

Bottom side is cathode, top side is anode.

Die Type	Nominal Size (Inch)	A Inch (mm) +/003 (.077)	B Inch (mm) +/003 (.077)	C Inch (mm) +/001 (.026)
ULTRAFAST RECOVERY	.120	.120 (3.05)	.094 (2.38)	.010 (0.254)

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SD120UF500X45

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